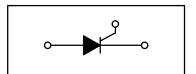
Silicon Controlled Rectifiers

PNPN devices designed for high volume, line-powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits. Supplied in an inexpensive TO-226AA (TO-92) package which is readily adaptable for use in automatic insertion equipment.

- Sensitive Gate Trigger Current 200 μA Maximum
- Low Reverse and Forward Blocking Current 100 μA Maximum, T_C = 125°C
- Low Holding Current 5 mA Maximum
- · Glass-Passivated Surface for Reliability and Uniformity

BRY55-30* thru 600*

SCRs 0.8 AMPERE RMS 30 TO 600 VOLTS





MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Forward and Reverse Blocking Voltage ⁽¹⁾ (RGK = 1000 Ω, TJ = 25 to 125°C) Marking: BRY55-1 BRY55-30 -2 BRY55-60 -3 BRY55-100 -4 BRY55-200 -6 BRY55-400 -7 BRY55-500 -8 BRY55-600	V _{RRM} , V _{DRM}	30 60 100 200 400 500 600	Volts
Forward Current RMS (All Conduction Angles)	IT(RMS)	0.8	Amp
Peak Forward Surge Current, T _A = 25°C (1/2 Cycle, Sine Wave, 60 Hz)	ITSM	8	Amps
Circuit Fusing Considerations, T _A = 25°C (t = 8.3 ms)	l ² t	0.15	A ² s
Peak Gate Power — Forward, T _A = 25°C	P _{GM}	0.1	Watt
Peak Gate Current Forward, T _A = 25°C (300 μs, 120 PPS)	IGFM	1	Amp
Peak Gate Voltage — Reverse	^V GRM	5	Volts
Operating Junction Temperature Range @ Rated V _{RRM} and V _{DRM}	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
Lead Solder Temperature (<1.5 mm from case, 10 s max.)		+230	°C

^{*}European part numbers only. Package is Case 29 with Leadform 18.

^{1.} V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



BRY55-30 thru 600

THERMAL CHARACTERISTICS

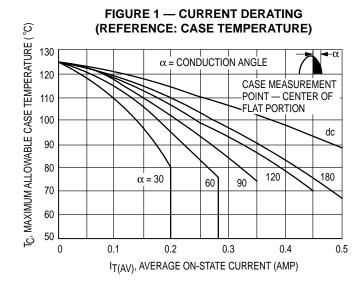
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	75	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C, R_{GK} = 1000 Ω unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit
Peak Forward Blocking Current (V _D = Rated V _{DRM} @ T _C = 125°C)		I _{DRM}	_	100	μΑ
Peak Reverse Blocking Current (V _R = Rated V _{RRM} @ T _C = 125°C)		I _{RRM}		100	μΑ
Forward "On" Voltage ⁽¹⁾ (I _{TM} = 1 A Peak @ T _A = 25°C)		V _{TM}		1.7	Volts
Gate Trigger Current (Continuous dc) ⁽²⁾ (Anode Voltage = 7 Vdc, R _L = 100 Ohms)	T _C = 25°C	IGT	_	200	μΑ
Gate Trigger Voltage (Continuous dc) (Anode Voltage = 7 Vdc, R _L = 100 Ohms) (Anode Voltage = Rated V _{DRM} , R _L = 100 Ohms)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$ $T_{C} = 125^{\circ}C$	Vgт	— — 0.1	0.8 1.2 —	Volts
Holding Current (Anode Voltage = 7 Vdc, initiating current = 20 mA)	$T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$	lн	_	5 10	mA

- 1. Forward current applied for 1 ms maximum duration, duty cycle ≤ 1%.
- 2. R_{GK} current is not included in measurement.

3. MÄRKING: BRY55-30 = BRY55-1 BRY55-60 = BRY55-2 BRY55-100 = BRY55-3 BRY55-200 = BRY55-4 BRY55-400 = BRY55-6 BRY55-500 = BRY55-7 BRY55-600 = BRY55-8



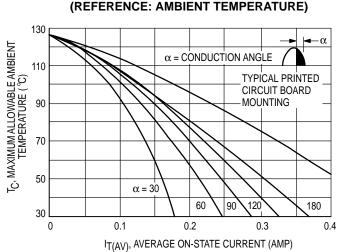
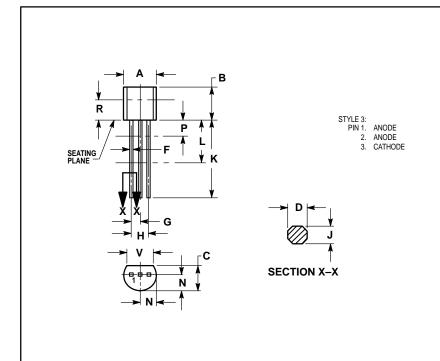


FIGURE 2 — CURRENT DERATING

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

CASE 029-04 (TO-226AA)

BRY55-30 thru 600

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